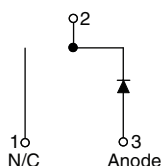


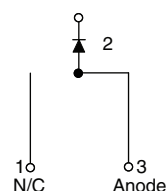
Hyperfast Rectifier, 30 A FRED Pt™

30ETH06SPbF



D²PAK

30ETH06-1PbF



TO-262

FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- Low leakage current
- 125 °C operating junction temperature
- Dual diode center tap
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for Q101 level



RoHS*
COMPLIANT

DESCRIPTION/APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC-DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

PRODUCT SUMMARY

t_{rr} (typical)	28 ns
$I_{F(AV)}$	30 A
V_R	600 V

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Peak repetitive reverse voltage	V_{RRM}		600	V
Average rectified forward current	$I_{F(AV)}$	$T_C = 103\text{ °C}$	30	A
Non-repetitive peak surge current	I_{FSM}	$T_J = 25\text{ °C}$	200	
Operating junction and storage temperatures	T_J, T_{Stg}		- 65 to 175	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	$I_R = 100\text{ }\mu\text{A}$	600	-	-	V
Forward voltage	V_F	$I_F = 30\text{ A}$	-	2.0	2.6	
		$I_F = 30\text{ A}, T_J = 150\text{ °C}$	-	1.34	1.75	
Reverse leakage current	I_R	$V_R = V_R$ rated	-	0.3	50	μA
		$T_J = 150\text{ °C}, V_R = V_R$ rated	-	60	500	
Junction capacitance	C_T	$V_R = 600\text{ V}$	-	33	-	pF
Series inductance	L_S	Measured lead to lead 5 mm from package body	-	8.0	-	nH

* Pb containing terminations are not RoHS compliant, exemptions may apply

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t _{rr}	I _F = 1.0 A, dI _F /dt = 50 A/μs, V _R = 30 V	-	28	35	ns
		T _J = 25 °C	-	31	-	
		T _J = 125 °C	-	77	-	
Peak recovery current	I _{RRM}	T _J = 25 °C	-	3.5	-	A
		T _J = 125 °C	-	7.7	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C	-	65	-	nC
		T _J = 125 °C	-	345	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C
Thermal resistance, junction to case per leg	R _{thJC}		-	0.7	1.1	°C/W
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	70	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	
Weight			-	2.0	-	g
			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style D ² PAK	30ETH06S			
		Case style TO-262	30ETH06-1			

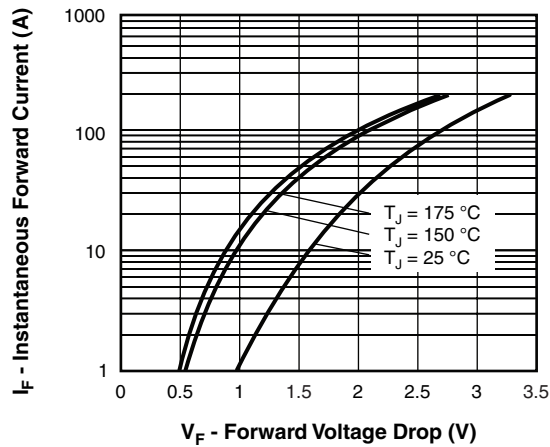


Fig. 1 - Typical Forward Voltage Drop Characteristics

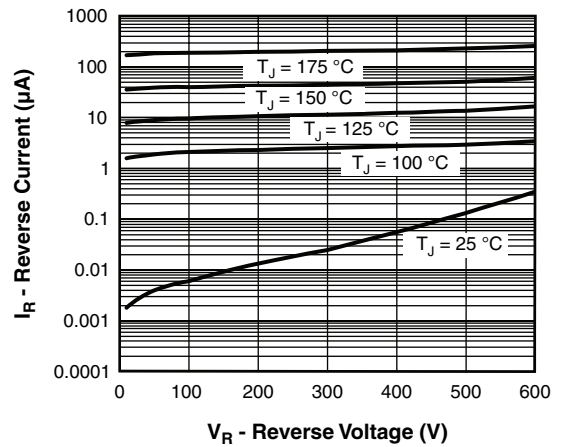


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

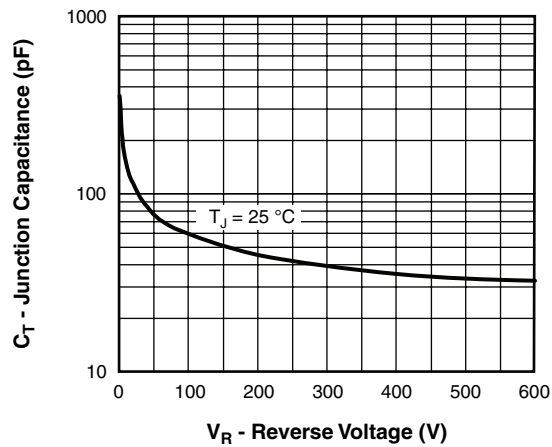


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

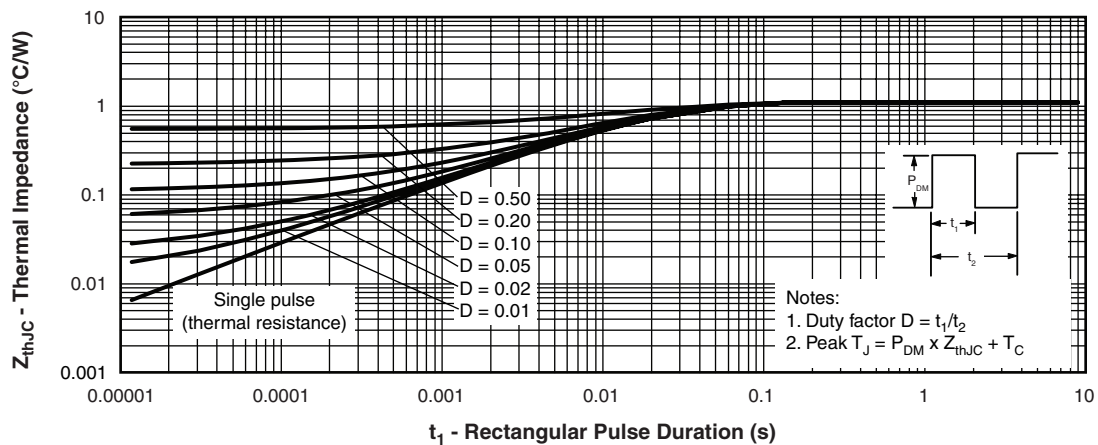


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

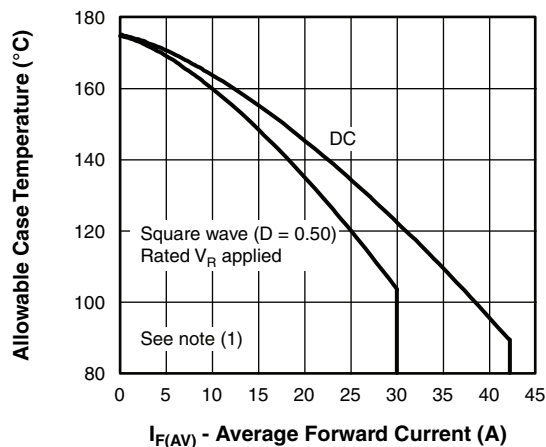


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

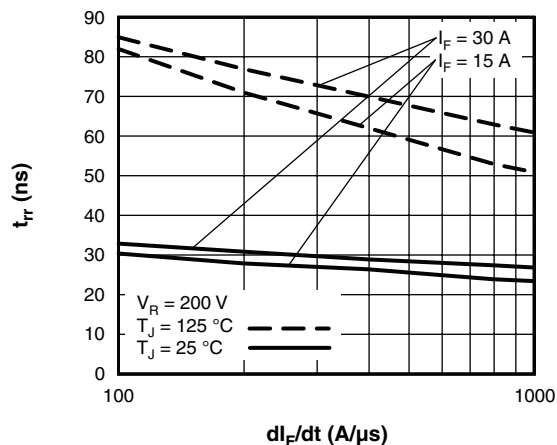


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

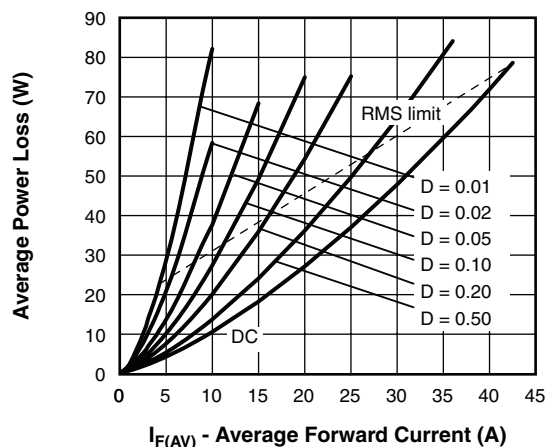


Fig. 6 - Forward Power Loss Characteristics

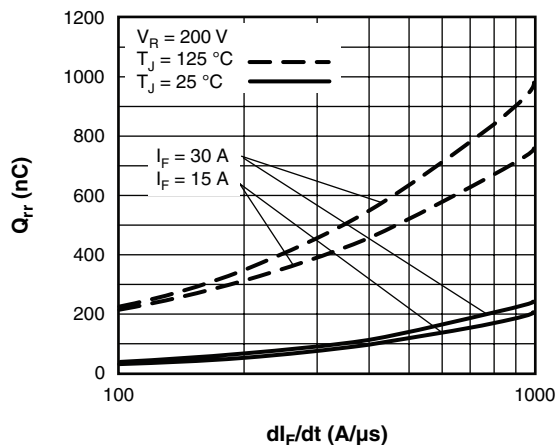


Fig. 8 - Typical Stored Charge vs. dI_F/dt

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 P_{dREV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R

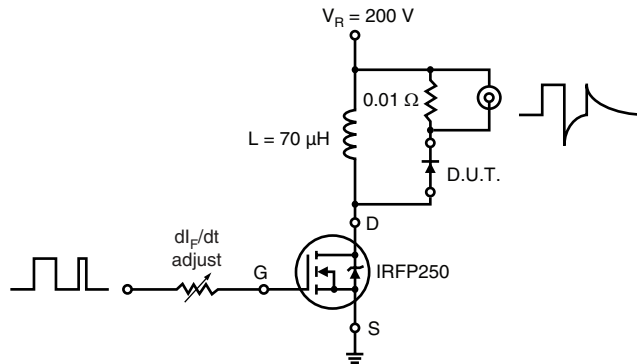


Fig. 9 - Reverse Recovery Parameter Test Circuit

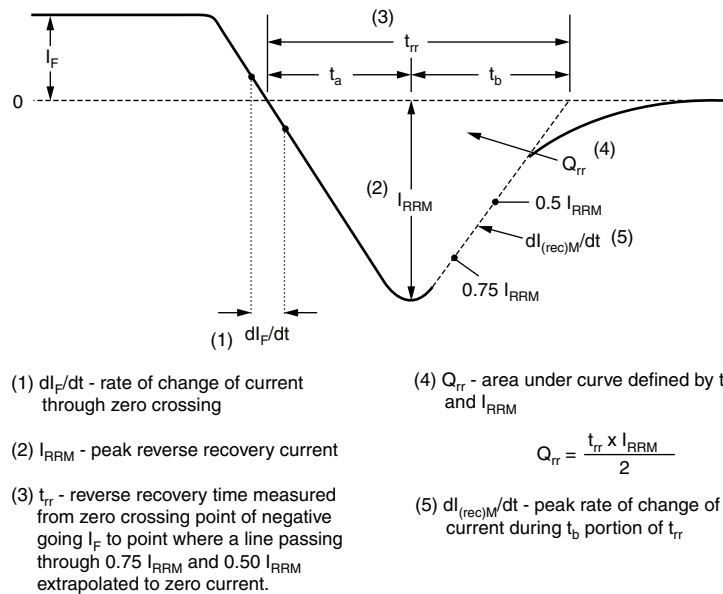


Fig. 10 - Reverse Recovery Waveform and Definitions

30ETH06SPbF/30ETH06-1PbF

Vishay High Power Products

Hyperfast Rectifier,
30 A FRED Pt™



ORDERING INFORMATION TABLE

Device code	30	E	T	H	06	S	TRL	PbF
	1	2	3	4	5	6	7	8

- | | | |
|----------|---|--|
| 1 | - | Current rating (30 = 30 A) |
| 2 | - | E = Single diode |
| 3 | - | T = TO-220, D ² PAK |
| 4 | - | H = Hyperfast recovery |
| 5 | - | Voltage rating (06 = 600 V) |
| 6 | - | <ul style="list-style-type: none">• S = D²PAK• -1 = TO-262 |
| 7 | - | <ul style="list-style-type: none">• None = Tube (50 pieces)• TRL = Tape and reel (left oriented, for D²PAK package)• TRR = Tape and reel (right oriented, for D²PAK package) |
| 8 | - | <ul style="list-style-type: none">• None = Standard production• PbF = Lead (Pb)-free |

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95014
Part marking information	http://www.vishay.com/doc?95008
Packaging information	http://www.vishay.com/doc?95032



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